



BC856A - BC858C

PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR

Features

- Ideally Suited for Automatic Insertion
- Complementary NPN Types Available (BC846-BC848)
- For Switching and AF Amplifier Applications
- Qualified to AEC-Q101 Standards for High Reliability
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)

Mechanical Data

- Case: SOT-23 .
- Case Material: Molded Plastic. UL Flammability . Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Pin Connections: See Diagram
- Marking Codes: See Table Below & Diagram on Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.008 grams (approximate)

Marking Code (Note 2)											
Type Marking Type Marking											
BC856A	3A, K3A	BC857C	3G, K3G								
BC856B	3B, K3B	BC858A	3J, K3J, K3A, K3V								
BC857A	3E, K3V, K3A	BC858B	3K, K3K, K3B, K3W								
BC857B	3F, K3W, K3B	BC858C	3L, K3L, K3G								

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SOT-23									
Dim	Min	Max							
Α	0.37	0.51							
В	1.20	1.40							
c	2.30	2.50							
D	0.89	1.03							
Е	0.45	0.60							
G	1.78	2.05							
н	2.80	3.00							
J	0.013	0.10							
к	0.903	1.10							
L	0.45	0.61							
М	0.085	0.180							
α	0°	8°							
All Din	All Dimensions in mm								

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage	BC856 BC857 BC858	V _{CBO}	-80 -50 -30	V		
Collector-Emitter Voltage	BC856 BC857 BC858	V _{CEO}	-65 -45 -30	V		
Emitter-Base Voltage		V _{EBO}	-5.0	V		
Collector Current		Ι _C	-100	mA		
Peak Collector Current		I _{CM}	-200	mA		
Peak Emitter Current		I _{EM}	-200	mA		
Power Dissipation (Note 1)		P _d	300	mW		
Thermal Resistance, Junction to Ambient (Note 1)		R _{0JA}	417	°C/W		
Operating and Storage Temperature Range		T _j , T _{STG}	-65 to +150	°C		

Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, Notes: 1.

which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. 2

Current gain subgroup "C" is not available for BC856.

3.

No purposefully added lead. Halogen and Antimony Free. Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 4. V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.

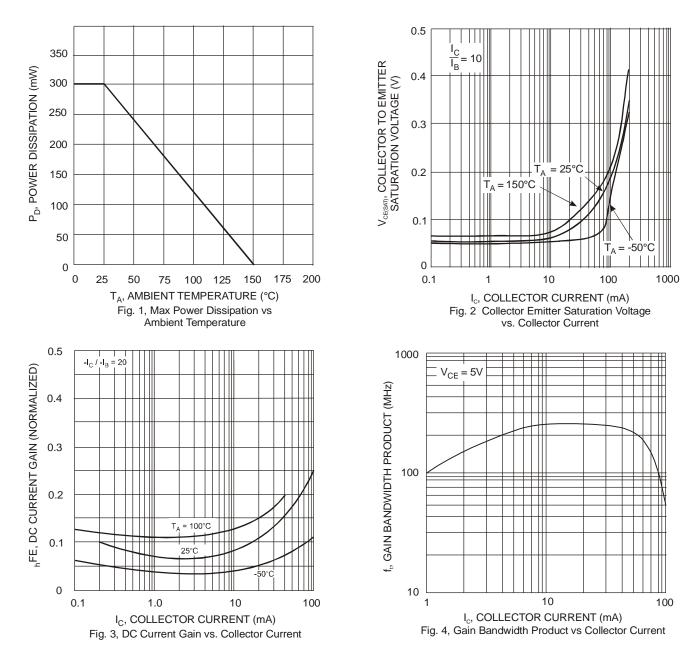


Electrical Characteristics @T_A = 25°C unless otherwise specified

Character	istic	Symbol	Min	Тур	Max	Unit	Test Condition		
Collector-Base Breakdown Voltag	e (Note 5) BC856 BC857 BC858	V _{(BR)CBO}	-80 -50 -30			v	$I_{\rm C} = 10 \mu A, I_{\rm B} = 0$		
Collector-Emitter Breakdown Volta	V _{(BR)CEO}	-65 -45 -30			V	I _C = 10mA, I _B = 0			
Emitter-Base Breakdown Voltage	(Note 5)	V _{(BR)EBO}	-5	—	—	V	$I_{E} = 1 \mu A, I_{C} = 0$		
H-Parameters Small Signal Current Gain Input Impedance	h _{fe} h _{fe} h _{fe} h _{ie}	 	200 330 600 2.7	 	— — κΩ				
Input Impedance Current Gain Group A B C Output Admittance Current Gain Group A B C Reverse Voltage Transfer Ratio Current Gain Group A				4.5 8.7 18 30 60		kΩ kΩ μS μS	V _{CE} = -5.0V, I _C = -2.0mA, f = 1.0kHz		
DC Current Gain (Note 5)	h _{re} h _{re} h _{re}	 125	1.5x10 ⁻⁴ 2x10 ⁻⁴ 3x10 ⁻⁴ 180	 					
DC Current Gain (Note 5)	h _{FE}	220 420	290 520	250 475 800	_	$V_{CE} = -5.0V, I_C = -2.0mA$			
Collector-Emitter Saturation Voltag	V _{CE(SAT)}	_	-75 -250	-300 -650	mV	$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -0.5mA $I_{\rm C}$ = -100mA, $I_{\rm B}$ = -5.0mA			
Base-Emitter Saturation Voltage (I	Note 5)	$V_{BE(SAT)}$	_	-700 -850		mV	$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -0.5mA $I_{\rm C}$ = -100mA, $I_{\rm B}$ = -5.0mA		
Base-Emitter Voltage (Note 5)	V _{BE(ON)}	-600 —	-650 —	-750 -820	mV	V_{CE} = -5.0V, I_{C} = -2.0mA V_{CE} = -5.0V, I_{C} = -10mA			
Collector-Cutoff Current (Note 5) BC856 BC857 BC858			 		-15 -15 -15 -15 -4.0	nA nA nA µA	$V_{CE} = -80V V_{CE} = -50V V_{CE} = -30V V_{CB} = -30V V_{CB} = -30V, T_A = 150°C$		
Gain Bandwidth Product	f⊤	100	200	_	MHz	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = \text{-5.0V}, \ I_{\text{C}} = \text{-10mA}, \\ f = 100 \text{MHz} \end{array}$			
Collector-Base Capacitance	C _{CBO}	_	3	_	pF	V _{CB} = -10V, f = 1.0MHz			
Noise Figure		NF	_	2	10	dB	$\label{eq:Vce} \begin{split} V_{CE} &= -5.0V, \ I_C = 200 \mu A, \\ R_S &= 2 k \Omega, \ f = 1 k H z, \ \Delta f = 200 H z \end{split}$		

Notes: 5. Short duration pulse test used to minimize self-heating effect.







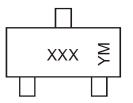
Ordering Information (Note 6)

Device*	Packaging	Shipping			
BC85xx-7-F	SOT-23	3000/Tape & Reel			

xx = device type, e.g. BC856A-7-F.

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1), e.g. K3A = BC856A YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
Month	Jan	Fe	b I	Mar	Apr	Мау	Ju	n	Jul	Aug	Sep	Oc	t	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		Ν	D

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